3.3 V 16-bit registered transceiver; 3-state Rev. 3 — 1 October 2018

1. General description

The 74LVT16543A is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V. The device can be used as two 8-bit transceivers or one 16-bit transceiver.

The 74LVT16543A contains two sets of eight D-type latches, with separate control pins for each set. Using data flow from A to B as an example, when the A-to-B enable (nEAB) input and the A-to-B latch enable (nEAB) input are LOW, the A-to-B path is transparent.

A subsequent LOW-to-HIGH transition of the nLEAB signal puts the A data into the latches where it is stored and the B outputs no longer change with the A inputs. With nEAB and nOEAB both LOW, the 3-State B output buffers are active and display the data present at the outputs of the A latches.

Control of data flow from B to A is similar, but using the nEBA, nLEBA, and nOEBA inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

2. Features and benefits

- 16-bit universal bus interface
- 3-state buffers
- Input and output interface capability to systems at 5 V supply
- TTL input and output switching levels
- Output capability: +64 mA/-32 mA
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-state
- Power-up reset
- No bus current loading when output is tied to 5 V bus
- Latch-up protection:
 - JESD78B Class II exceeds 500 mA
- ESD protection:
 - HBM: JESD22-A114F exceeds 2000 V
 - MM: JESD22-A115-A exceeds 200 V

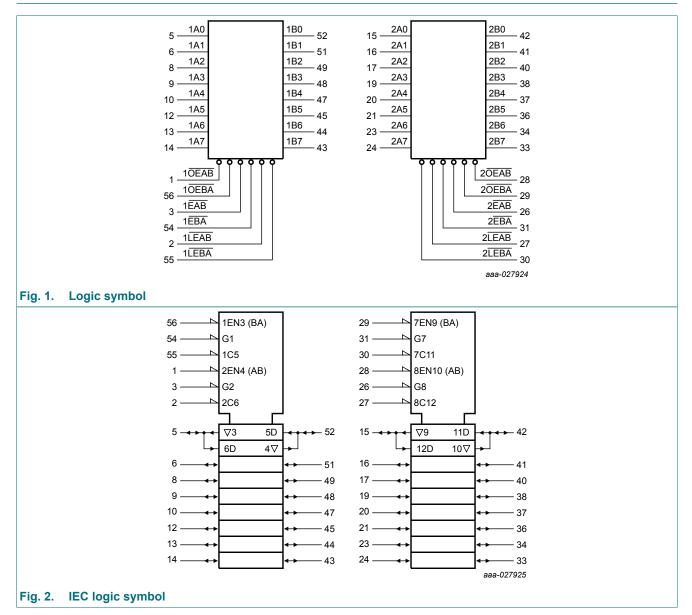
3. Ordering information

Table 1. Ordering information

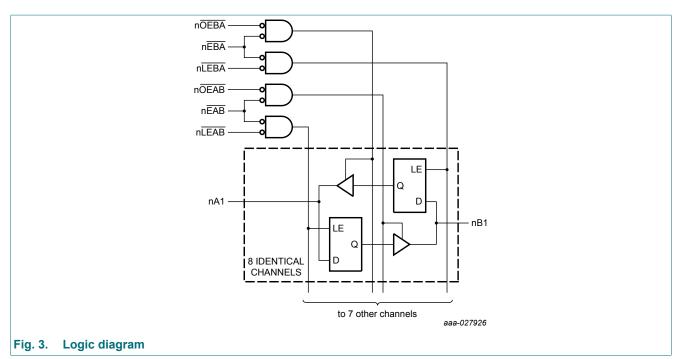
Type number	Package							
	Temperature range	Name	Description	Version				
74LVT16543ADL	-40 °C to +85 °C	SSOP56	plastic shrink small outline package; 56 leads; body width 7.5 mm	SOT371-1				
74LVT16543ADGG	-40 °C to +85 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 6.1 mm	SOT364-1				

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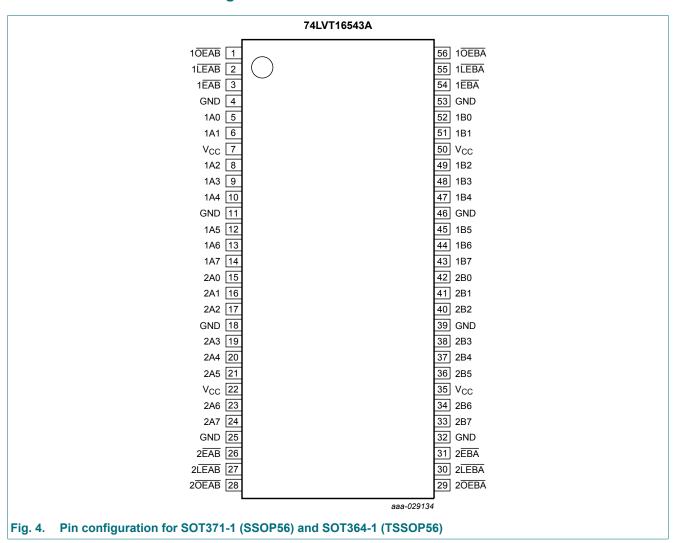
4. Functional diagram



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5. Pinning information



5.1. Pinning

5.2. Pin description

Table 2. Pin description							
Symbol	Pin	Description					
1A0, 1A1, 1A2, 1A3, 1A4, 1A5, 1A6, 1A7	5, 6, 8, 9, 10, 12, 13, 14	data inputs/outputs					
2A0, 2A1, 2A2, 2A3, 2A4, 2A5, 2A6, 2A7	15, 16, 17, 19, 20, 21, 23, 24	data inputs/outputs					
1B0, 1B1, 1B2, 1B3, 1B4, 1B5, 1B6, 1B7	52, 51, 49, 48, 47, 45, 44, 43	data inputs/outputs					
2B0, 2B1, 2B2, 2B3, 2B4, 2B5, 2B6, 2B7	42, 41, 40, 38, 37, 36, 34, 33	data inputs/outputs					
10EAB, 10EBA, 20EAB, 20EBA	1, 56, 28, 29	A to B / B to A output enable inputs (active LOW)					
1EAB, 1EBA, 2EAB, 2EBA	3, 54, 26, 31	A to B / B to A enable inputs (active LOW)					
1LEAB, 1LEBA, 2LEAB, 2LEBA	2, 55, 27, 30	A to B / B to A latch enable inputs (active LOW)					
GND	4, 11, 18, 25, 32, 39, 46, 53	ground (0 V)					
V _{CC}	7, 22, 35, 50	supply voltage					

6. Functional description

Table 3. Function selection [1]

Inputs			Outputs	Status	
nOEAB or nOEBA	nEAB or nEBA	nLEAB or nLEBA	nAn or nBn	nBn or nAn	
Н	Х	X	Х	Z	Disabled
Х	Н	X	Х	Z	Disabled
L	1	L	h	Z	Disabled + Latch
L	1	L	1	Z	Disabled + Latch
L	L	1	h	Н	Latch + Display
L	L	1	1	L	Latch + Display
L	L	L	Н	Н	Transparent
L	L	L	L	L	Transparent
L	L	Н	Х	NC	Hold

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH transition of $n\overline{LEAB}$, $n\overline{LEBA}$, $n\overline{EAB}$ and $n\overline{EBA}$;

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH transition of nLEAB, nLEBA, nEAB and nEBA;

X = don't care;

↑ = LOW-to-HIGH transition of $n\overline{\text{LEAB}}$, $n\overline{\text{LEBA}}$, $n\overline{\text{EAB}}$ or $n\overline{\text{EBA}}$;

NC = no change;

Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+7.0	V
Vo	output voltage	output in OFF or HIGH state	[1]	-0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0		-50	-	mA
I _{ОК}	output clamping current	V _O < 0		-50	-	mA
I _O	output current	output in LOW state		-	128	mA
		output in HIGH state		-64	-	mA
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature		[2]	-	+150	°C

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Мах	Unit			
V _{CC}	supply voltage		2.7	3.6	V			
VI	input voltage		0	5.5	V			
T _{amb}	ambient temperature	in free air	-40	+85	°C			
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	10	ns/V			

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Мах	Unit
V _{IK}	input clamping voltage	V _{CC} = 2.7 V; I _{IK} = -18 mA	-	-0.85	-1.2	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
V _{OH}	HIGH-level output voltage	V_{CC} = 2.7 V to 3.6 V; I _{OH} = -100 µA	V _{CC} - 0.2	V _{CC}	-	V
		V _{CC} = 2.7 V; I _{OH} = -8 mA	2.4	2.54	-	V
		V _{CC} = 3.0 V; I _{OH} = -32 mA	2.0	2.36	-	V
V _{OL}	LOW-level output voltage	V _{CC} = 2.7 V; I _{OL} = 100 μA	-	0.07	0.2	V
		V _{CC} = 2.7 V; I _{OL} = 24 mA	-	0.3	0.5	V
		V _{CC} = 3.0 V; I _{OL} = 16 mA	-	0.2	0.4	V
		V _{CC} = 3.0 V; I _{OL} = 32 mA	-	0.3	0.5	V
		V _{CC} = 3.0 V; I _{OL} = 64 mA	-	0.35	0.55	V
I _{OH}	HIGH-level output current		-	-	-32	mA

Symbol	Parameter	Conditions		Min	Typ [1]	Max	Unit
I _{OL}	LOW-level output current	level output current current duty cycle \leq 50 %; f _i \geq 1 kHz		-	-	32	mA
		current duty cycle \leq 50 %; f _i \geq 1 kHz		-	-	64	mA
V _{OL(pu)}	power-up LOW-level output voltage	V_{CC} = 3.6 V; I _O = 1 mA; V _I = V _{CC} or GND [[2]	-	0.13	0.55	V
li –	input leakage current	control pins					
		V _{CC} = 0 V or 3.6 V; V _I = 5.5 V		-	0.1	10	μA
		V_{CC} = 3.6 V; V_{I} = V_{CC} or GND		-	0.1	±1	μA
		I/O data pins	3]				
		V _{CC} = 3.6 V; V _I = 5.5 V		-	0.5	20	μA
		$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = V_{CC}$		-	0.5	10	μA
		V _{CC} = 3.6 V; V _I = 0 V		-	1	-5	μA
I _{OFF}	power-off leakage current	V_{CC} = 0 V; V _I or V _O = 0 V to 4.5 V		-	1	±100	μA
I _{BHL}	bus hold LOW current	V _{CC} = 3.0 V; V _I = 0.8 V		75	130	-	μA
I _{BHH}	bus hold HIGH current	V _{CC} = 3.0 V; V _I = 2.0 V		-75	-140	-	μA
I _{BHLO}	bus hold LOW overdrive current	$V_{\rm CC} = 3.6 \text{ V}; \text{ V}_{\rm I} = 0 \text{ V} \text{ to } 3.6 \text{ V}$ [4]	4]	500	-	-	μA
I _{BHHO}	bus hold HIGH overdrive current	$V_{\rm CC} = 3.6 \text{ V}; \text{ V}_{\rm I} = 0 \text{ V} \text{ to } 3.6 \text{ V}$ [4]	4]	-	-	-500	μA
I _{CEX}	output high leakage current	output in HIGH-state when $V_O > V_{CC}$; $V_O = 5.5 V$; $V_{CC} = 3.0 V$		-	45	125	μA
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_{O} = 0.5 \text{ V to } V_{CC}; \qquad [\xi V_{I} = \text{GND or } V_{CC}; n\overline{\text{OE}} = \text{don't care}$	5]	-	35	±100	μA
I _{CC}	supply current	V_{CC} = 3.6 V; V_{I} = V_{CC} or GND; I_{O} = 0 A					
		outputs HIGH		-	0.07	0.12	mA
		outputs LOW		-	4.5	6	mA
		outputs disabled	6]	-	0.07	0.12	mA
ΔI _{CC}	additional supply current	per input pin; V_{CC} = 3.0 V to 3.6 V; one input = V_{CC} - 0.6 V; other inputs at V_{CC} or GND	7]	-	0.1	0.2	mA
CI	input capacitance	at control pins; $V_I = 0 V \text{ or } 3.0 V$		-	3	-	pF
C _{I/O}	input/output capacitance	at input/output data pins, outputs disabled; $V_{I/O} = 0$ V or 3.0 V		-	9	-	pF

[1]

All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C. For valid test results, data must not be loaded into the latches after applying power. [2]

[3] Unused pins at V_{CC} or GND.

This is the bus hold overdrive current required to force the input to the opposite logic state. This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. [4]

[5]

From V_{CC} = 1.2 V to V_{CC} = 3.0 V to 3.6 V a transition time of 100 µs is permitted. This parameter is valid for T_{amb} = +25 °C only. I_{CC} with the outputs disabled is measured with outputs pulled to V_{CC} or GND. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

[6]

[7]

10. Dynamic characteristics

Table 7. Dynamic characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 9.

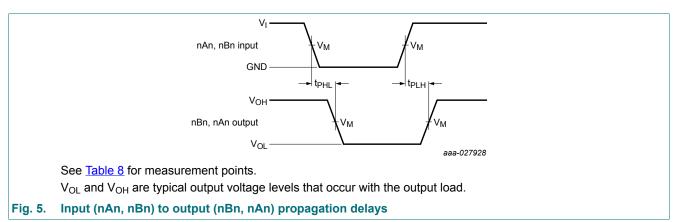
Symbol	Parameter	Conditions	Min	Typ [1]	Мах	Unit
t _{pd}	propagation delay	nAn to nBn or nBn to nAn; see Fig. 5	2]			
		V _{CC} = 2.7 V	-	-	4.4	ns
		V _{CC} = 3.3 V ± 0.3 V	1.0	2.2	3.7	ns
t _{pd}	propagation delay	nLEBA to nAn, nLEAB to nBn; see Fig. 6	2]			
		V _{CC} = 2.7 V	-	-	6.2	ns
		V _{CC} = 3.3 V ± 0.3 V	1.5	2.7	4.8	ns
PZH OFF-state to HIGH						
	propagation delay	V _{CC} = 2.7 V	-	-	6.1	ns
		V _{CC} = 3.3 V ± 0.3 V	1.5	2.8	4.6	ns
t _{PZL}	OFF-state to LOW	nOEBA to nAn, nOEAB to nBn; see Fig. 7				_
	propagation delay	V _{CC} = 2.7 V	-	-	6.6	ns
		V _{CC} = 3.3 V ± 0.3 V	1.5	2.6	5.0	ns
t _{PHZ}	HIGH to OFF-state	nOEBA to nAn, nOEAB to nBn; see Fig. 7				
	propagation delay	V _{CC} = 2.7 V	-	-	5.7	ns
		V _{CC} = 3.3 V ± 0.3 V	2.0	3.1	5.2	ns
t _{PLZ}	LOW to OFF-state	nOEBA to nAn, nOEAB to nBn; see Fig. 7				
	propagation delay	V _{CC} = 2.7 V	-	-	4.7	ns
		V _{CC} = 3.3 V ± 0.3 V	2.0	3.2	4.6	ns
t _{PZH}	OFF-state to HIGH	nEBA to nAn, nEAB to nBn; see Fig. 7				_
	propagation delay	V _{CC} = 2.7 V	-	-	6.1	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.5	2.9	4.8	ns
t _{PZL}	OFF-state to LOW	nEBA to nAn, nEAB to nBn; see Fig. 7				
	propagation delay	V _{CC} = 2.7 V	-	-	6.6	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.5	2.6	5.1	ns
t _{PHZ}	HIGH to OFF-state	nEBA to nAn, nEAB to nBn; see Fig. 7				
	propagation delay	V _{CC} = 2.7 V	-	-	5.7	ns
		V _{CC} = 3.3 V ± 0.3 V	2.0	3.1	5.1	ns
t _{PLZ}	LOW to OFF-state	nEBA to nAn, nEAB to nBn; see Fig. 7				
	$ \begin{array}{ c c c c c } \hline V_{CC} = 2.7 \ V & & & & & & \\ \hline V_{CC} = 3.3 \ V \pm 0.3 \ V & & & & & \\ \hline V_{CC} = 3.3 \ V \pm 0.3 \ V & & & & & \\ \hline & & & & & & \\ \hline & & & & &$	-	4.5	ns		
		$V_{CC} = 3.3 V \pm 0.3 V$	2.0	3.2	4.4 3.7 6.2 4.8 6.1 4.6 6.6 5.0 5.7 5.2 4.7 4.6 6.1 4.8 6.1 4.8 6.6 5.1 5.7 5.1	ns
t _{su(H)}	set-up time HIGH	nAn to nLEAB, nBn to nLEBA; see Fig. 8				
		V _{CC} = 2.7 V	0.5	-	-	ns
		V _{CC} = 3.3 V ± 0.3 V	0.8	0.4	-	ns
t _{su(L)}	set-up time LOW	nAn to nLEAB, nBn to nLEBA; see Fig. 8				_
		V _{CC} = 2.7 V	1.5	-	-	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.0	0.1	-	ns
t _{h(H)}	hold time HIGH					+
. /		V _{CC} = 2.7 V	0.5	-	-	ns
				0.2	-	ns

Symbol	Parameter	Conditions	Min	Typ [1]	Мах	Unit
t _{h(L)}	hold time LOW	nAn to nLEAB, nBn to nLEBA; see Fig. 8				
		V _{CC} = 2.7 V	1.3	-	-	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.2	0.4	-	ns
t _{su(H)}	set-up time HIGH	nAn to nEAB, nBn to nEBA; see Fig. 8				
		V _{CC} = 2.7 V	0.4	-	-	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	0.7	0.1	-	ns
t _{su(L)}	set-up time LOW	nAn to nEAB, nBn to nEBA; see Fig. 8				
		V _{CC} = 2.7 V	1.5	-	-	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.3	0.1	-	ns
t _{h(H)}	hold time HIGH	nAn to nEAB, nBn to nEBA; see Fig. 8				
		V _{CC} = 2.7 V	0.8	-	-	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.2	0.2	-	ns
t _{h(L)}	hold time LOW	nAn to nEAB, nBn to nEBA; see Fig. 8				
		V _{CC} = 2.7 V	1.4	-	-	ns
		$V_{CC} = 3.3 V \pm 0.3 V$	1.3	0.4	-	ns
t _{WL}	pulse width LOW	nLEAB and nLEBA; see Fig. 6				
		V _{CC} = 2.7 V	1.8	-	-	ns
		$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	1.8	1.0	-	ns

[1] Typical values are measured at T_{amb} = 25 $^\circ C$ and V_{CC} = 3.3 V

[2] t_{pd} is the same as t_{PLH} and t_{PHL}

10.1. Waveforms and test circuit



3.3 V 16-bit registered transceiver; 3-state

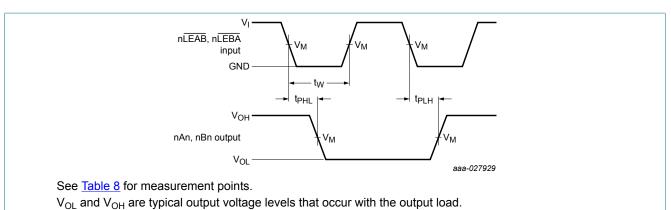
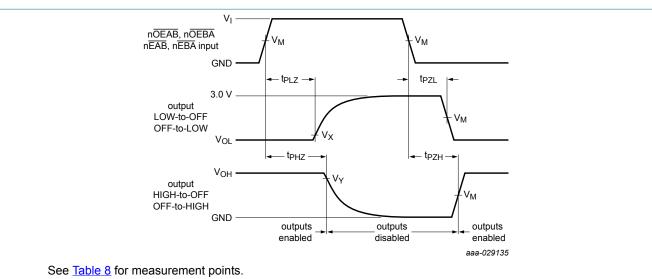
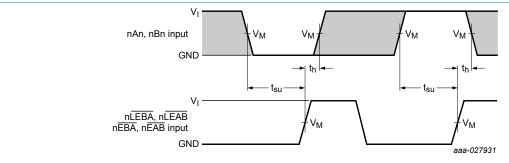


Fig. 6. Input (nLEAB, nLEBA) to output (nBn, nAn) propagation delays and pulse width LOW



 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 7. 3-state output enable and disable times



See Table 8 for measurement points.

The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig. 8. Data set-up and hold times for the inputs nAn and nBn to nLEBA, nLEAB, nEBA and nEAB inputs

Table 8. Measurement points

Input		Output		
VI	V _M	V _M	V _x	Vy
2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} - 0.3 V

3.3 V 16-bit registered transceiver; 3-state

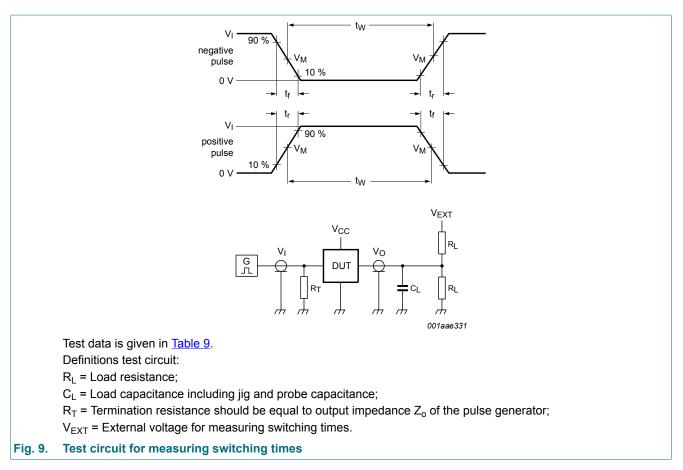


Table 9. Test data

Input			Load		V _{EXT}			
VI	f _i	tw	t _r , t _f	RL	CL	PHZ, TPZH TPLZ, TPZL TPLH, TPHL		
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	500 Ω	50 pF	GND	6 V	open

11. Package outline

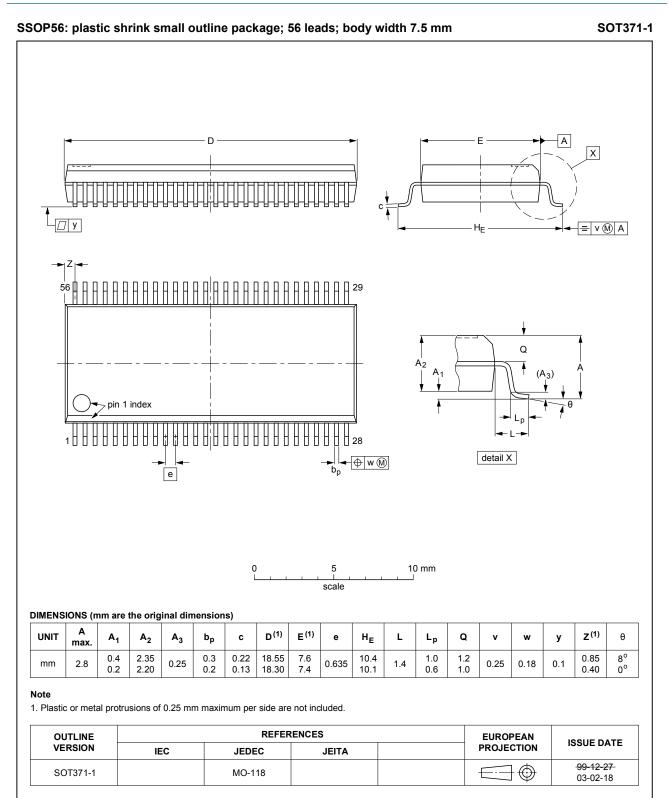


Fig. 10. Package outline SOT371-1 (SSOP56)

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74LVT16543A

3.3 V 16-bit registered transceiver; 3-state

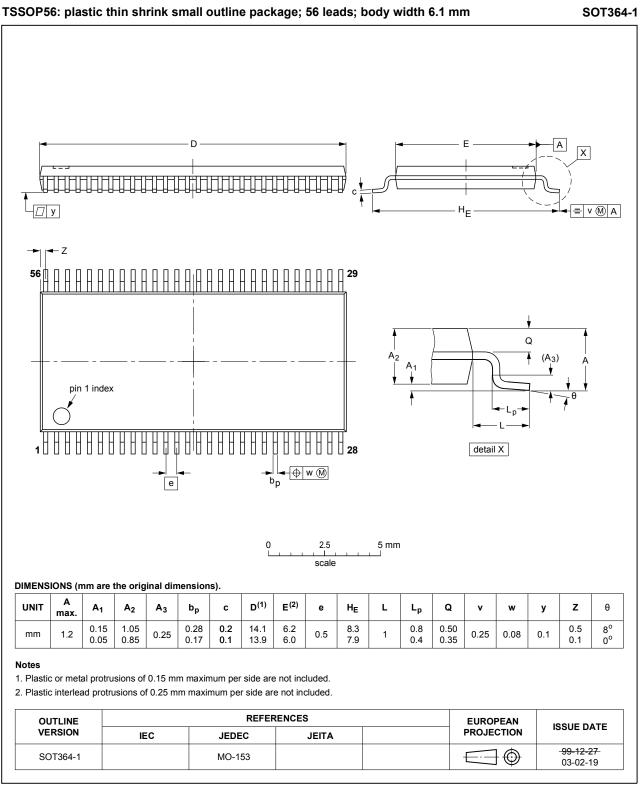


Fig. 11. Package outline SOT364-1 (TSSOP56)

⁷⁴LVT16543A

12. Abbreviations

Acronym	Description	
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
MIL	Military	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

13. Revision history

Table 11. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVT16543A v.3	20181001	Product data sheet	-	74LVT16543A v.2		
Modifications:	Nexperia.	The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate.				
74LVT16543A v.2	19980219	Product specification	-	74LVT16543A v.1		
74LVT16543A v.1	-	Product specification		-		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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